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|   | <h2>HGTP12N60C3</h2> |
| | <p>Hersteller-Teilenummer: HGTP12N60C3</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: IGBT 600V 24A 104W TO220AB</p> <p>Datenblätter: 1.HGTP12N60C3.pdf 2.HGTP12N60C3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 20024 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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|---|---|
| Teilenummer | HGTP12N60C3 |
| Hersteller | Fairchild/ON Semiconductor |
| Beschreibung | IGBT 600V 24A 104W TO220AB |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-IGBTs- |
| Teilstatus | 20024 pcs Stock |
| Serie | - |
| Eingabetyp | Standard |
| Betriebstemperatur | -40°C ~ 150°C (TJ) |
| Befestigungsart | Through Hole |
| Leistung - max | 104W |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Strom - Kollektor (Ic) (max) | 24A |
| Spannung - Kollektor-Emitter-Durchbruch (max) | 600V |
| IGBT-Typ | - |
| VCE (on) (Max) @ Vge, Ic | 2V @ 15V, 12A |
| Strom - Collector Pulsed (Icm) | 96A |
| Schaltenergie | 380µJ (on), 900µJ (off) |
| Gate-Ladung | 48nC |
| Td (ein / aus) bei 25 ° C | - |
| Testbedingung | - |
| Verpackung | Tube |

HGTP12N60C3 ist neu im Original, Suche HGTP12N60C3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGTP12N60C3 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage HGTP12N60C3: Info@Y-IC.com

Sie können auch interessiert sein:

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|--|--|--|---|
|  <p>HGTP12N60C3 AMI Semiconductor / ON Semiconductor IGBT 600V 24A 104W TO220AB</p> |  <p>HGTP12N60C3D Fairchild/ON Semiconductor IGBT 600V 24A 104W TO220AB</p> |  <p>HGTP14N36G3VL FSC HGTP14N36G3VL FSC</p> |  <p>HGTP12N60B3 G12N60B3 FSC HGTP12N60B3 G12N60B3 FSC</p> |
|  <p>HGTP12N60C3D AMI Semiconductor / ON Semiconductor IGBT 600V 24A 104W TO220AB</p> |  <p>HGTP12N60A4D AMI Semiconductor / ON Semiconductor IGBT 600V 54A 167W TO220AB</p> |  <p>HGTP12N60B3D Intersil/FAIRCHILD HGTP12N60B3D Intersil/FAIRCHILD</p> |  <p>HGTP14N40F3VL FAIRCHILD HGTP14N40F3VL FAIRCHILD</p> |

heiße Teile

Mehr

| | | | | |
|-----------------|-----------------|-----------------|-----------------|-----------------|
| ⊗ HGTP40N60C3 | ↔ HGTP5N120BND | ⇒ HGTP5N120BND | D HGTP7N60A4 | ⇒ HGTP7N60A4 |
| ⊣ HGTP7N60A4D | ⊗ HGTP7N60A4D | D HGTP30N60A4D | ⇒ HGTP40N60 | ⇒ HGTP40N60A4D |
| ⊗ HGTP10N120BN | ⊣ HGTP10N120BN | ⊗ HGTP10N40C1 | ↔ HGTP10N40E1D | ⇒ HGTP10N40F1D |
| D HGTP10N50C1 | ⊗ HGTP11N120CN | ⊣ HGTP11N120CND | ⊗ HGTP12N60A4 | ⇒ HGTP12N60A4 |
| ⇒ HGTP12N60A4D | ↔ HGTP12N60A4D | ⊗ HGTP12N60B3 | ⊣ HGTP12N60B3D | ⇒ HGTP12N60C3 |
| ↔ HGTP14N36G3VL | ⇒ HGTP14N40F3VL | D HGTP14N41G3 | ⊗ HGTP15N120C3 | ⊣ HGTP15N40C1 |
| ⊗ HGTP15N50E1 | D HGTP1N120BND | ⇒ HGTP1N120CND | ↔ HGTP20N35G3VL | ⇒ HGTP20N36G3VL |
| ⊣ HGTP20N60A4 | ⊗ HGTP20N60A4 | ↔ HGTP20N60B3 | ⇒ HGTP20N60B3D | ⇒ HGTP20N60C3 |
| ⊗ HGTP20N60C3D | ⊣ HGTP2N120BN | ⊗ HGTP2N120BND | D HGTP2N120CN | ⇒ HGTP2N120CN |
| ↔ HGTP2N120CND | ⊗ HGTP3N60A4 | ⊣ HGTP3N60A4 | ⊗ HGTP5N120BND | ⇒ HGTP5N120BND |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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